NSN 5962-01-313-0662

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View Online at https://aerobasegroup.com/nsn/5962-01-313-0662

Body Length:
Between 1.430 inches and 1.485 inches
Body Width:
Between 0.245 inches and 0.310 inches
Body Height:
Between 0.080 inches and 0.160 inches
Maximum Power Dissipation Rating:
660.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and hermetically sealed and static operation and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Criticality Code Justification:
Feat
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Nuclear hardness critical item
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

N/a

28 printed circuit

Shelf Life:

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Demilitarization:

Yes - demil/mli

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